

Class Subclass

PATENT NUMBER

U.S. UTILITY Patent Application
O.I.P.E. PATENT DATE

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Fully-depleted-collector silicon-on-insulator (SOI) bipolar transistor useful alone or in SOI BiCMOS

	ISSUING CLASSIFICATION																		
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TERMINAL		DRAWINGS		CLAIMS ALLOWED		
DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
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WARNING: The information disclosed herein may be res Possession outside the U.S. Patent & Traden					5, Sections 122, 181 and 368.	
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